



Amplifier, Power, 16W 1.3-2.5 GHz

MAAP-000076-PKG001 **Advance Datasheet**

Features

- 16 Watt Saturated Output Power Level
- Variable Drain Voltage (8-10V) Operation
- MSAG Process

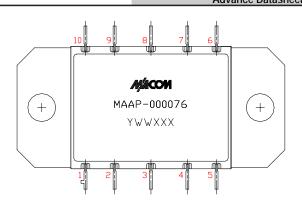
Primary Applications

- Radio Communications
- SatCom

Description

The MAAP-000076-PKG001 is a 2-stage 16W power amplifier with on-chip bias networks in a 10 lead flange-mount ceramic package, allowing easy assembly. The package is hermetic and provides an excellent thermal path. This product is fully matched to 50 ohms on both the input and output. External DC blocking capacitors are not required since they are incorporated into the MMIC design. It can be used as a power amplifier stage or as a driver stage in high power applications.

Fabricated using M/A-COM's repeatable, high performance and highly reliable GaAs Multifunction Self-Aligned Gate (MSAG™) Process, each device is 100% RF tested on wafer to ensure performance compliance.



Pin#	Description		
1	VGG		
2	N/C		
3	RF IN		
4	N/C		
5	VGG		
6	VDD		
7	N/C		
8	RF OUT		
9	N/C		
10	VDD		

Also Available in:

Description	Die	Ceramic Pkg Sample Board	Die Sample Board
Part Number	MAAPGM0076-DIE	MAAP-000076-SMB001	MAAP-000076-SMB004

Electrical Characteristics: $T_C = 45^{\circ}C^1$, $Z_0 = 50 \Omega$, $V_{DD} = 10V$, $I_{DQ} = 3.8A^2$, $P_{in} = 24$ dBm, $R_G = 30 \Omega$

Parameter	Symbol	Typical	Units	
Bandwidth	f	1.3-2.5	GHz	
Output Power	P _{OUT}	42	dBm	
1-dB Compression Point	P1dB	41	dBm	
Small Signal Gain	G	25	dB	
Power Added Efficiency	PAE	29	%	
Input VSWR	VSWR	1.3:1		
Output VSWR	VSWR	1.6:1		
Gate Current	lgg	33	mA	
Drain Current, under RF Drive	I _{DD}	5.2	А	
2 nd Harmonic	2f	25	dBc	

- T_C = Case Temperature
- Adjust V_{GG} between -2.6 and -1.2V to achieve specified I_{DQ}.
- North America Tel: 800.366.2266 / Fax: 978.366.2266
 - Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
 - Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298





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Maximum Ratings ³

Parameter	Symbol	Absolute Maximum	Units	
Input Power	P _{IN} 29		dBm	
Drain Supply Voltage	V_{DD}	+12.0	V	
Gate Supply Voltage	V_{GG}	-3.0	V	
Quiescent Drain Current (No RF)	I _{DQ}	6.1	А	
Quiescent DC Power Dissipated (No RF)	P _{DISS}	60.8	W	
Junction Temperature	TJ	170	°C	
Storage Temperature	T _{STG}	-55 to +150	°C	

^{3.} Operation beyond these limits may result in permanent damage to the part.

Recommended Operating Conditions⁴

Characteristic	Symbol	Min	Тур	Max	Unit
Drain Voltage	V_{DD}	8.0	10	10	V
Gate Voltage	V_{GG}	-2.6	-2.0	-1.2	V
Input Power	P _{IN}		24	27	dBm
Junction Temperature	T _J			150	°C
Thermal Resistance	Θ _{JC}				°C/W
Case Temperature	T _C			Note 5	°C

- 4. Operation outside of these ranges may reduce product reliability.
- 5. Case Temperature = 150° C Θ_{JC}^{*} V_{DD}^{*} I_{DQ}

Operating Instructions

This device is static sensitive. Please handle with care. To operate the device, follow these steps.

- 1. Apply $V_{GG} = -2.7 \text{ V}$, $V_{DD} = 0 \text{ V}$.
- 2. Ramp V_{DD} to desired voltage, typically 10.0 V.
- 3. Adjust V_{GG} to set I_{DQ} , (approximately @ -2.2 V).
- 4. Set RF input.
- Power down sequence in reverse. Turn V_{GG} off last



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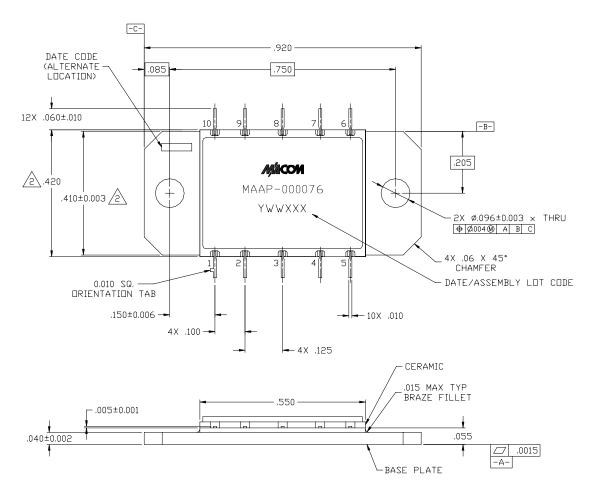


Figure 1. Package Dimensions

This is a high frequency, low thermal resistance package. The package consists of a cofired ceramic construction with a copper-tungsten base and iron-nickel-cobalt leads. The finish consists of electrolytic gold over nickel plate.

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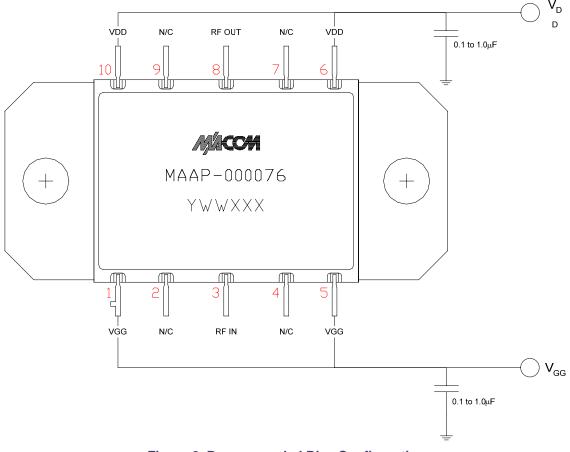


Figure 2. Recommended Bias Configuration

Assembly Instructions:

This flange mount style package provides a robust interface between a highly integrated GaAs MMIC device and a circuit board which may be assembled using conventional surface mount techniques. A thin shim made of a thermally and electrically conductive, ductile material must be used prior to installation of the ceramic package for proper thermal and electrical performance. Refer to **M/A-COM Application Note #M567*** for more information regarding shim material and mounting screw torque requirements.

For applications where surface mount components are to be installed after the ceramic package installation, this package will not be damaged when subjected to typical convection or IR oven reflow profiles. Refer to **M/A-COM Application Note #M538*** for maximum allowable reflow time and temperature. Alternatively, the package leads may be individually soldered. Whether an iron or hot gas soldering equipment is used, care should be taken to insure that the temperature is well controlled and electric static discharge (ESD) safe.

* Application Notes are available upon request.

Biasing Notes:

A negative bias must be applied to V_{GG} before applying a positive bias to V_{DD} to prevent damage to the
amplifier.

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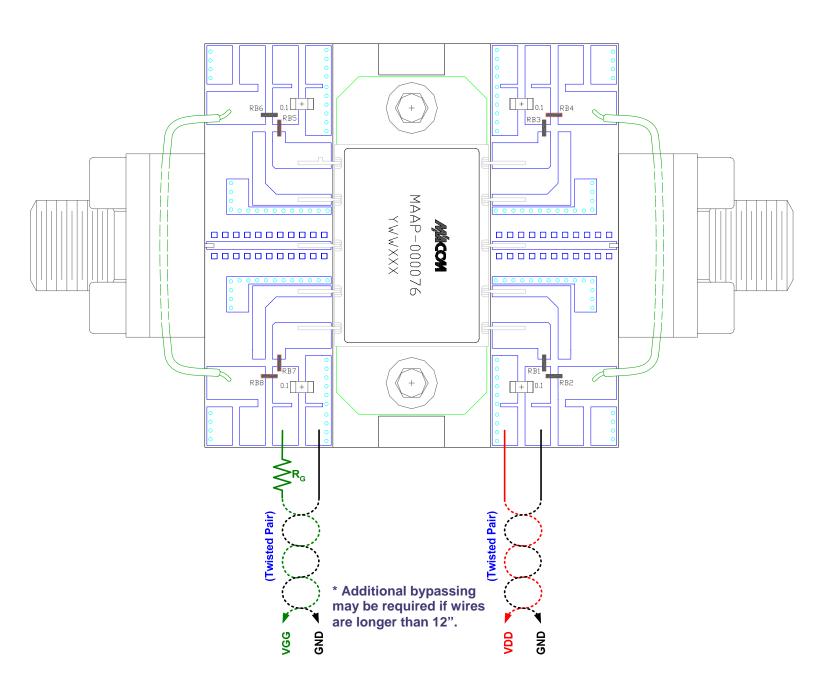


Figure 3. MAAP-000076-PKG001 Evaluation Board

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